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BCR10FM-12LB

600V - 10A - Triac

Medium Power Use

R07DS1107EJ0200 Rev.2.00 Oct. 10, 2017

Features

I_{T (RMS)}: 10 A
 V_{DRM}: 600 V
 Tj: 150 °C

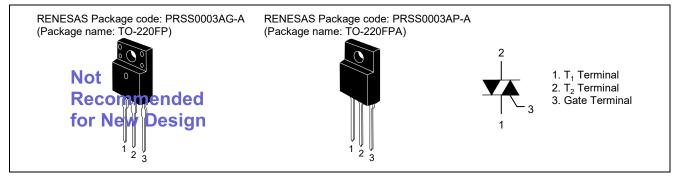
• I_{FGTI}, I_{RGTI}, I_{RGT III}: 30 mA(20mA) Note5

Insulated Type

• Planar Passivation Type

• Viso: 2000V

Outline



Application

Motor control, Heater control, Power supply, Solid state relay, and other general purpose AC control applications.

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
		12	
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	600	V
Non-repetitive peak off-state voltage ^{Note1}	V _{DSM}	720	V

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T (RMS)}	10	Α	Commercial frequency, sine full wave
				360°conduction,
				Tc = 111°C (#BB0, #BH0) Note2
				Tc = 103°C (#BG0) Note2
Surge on-state current	I _{TSM}	100	Α	50 Hz sinewave 1 full cycle, peak value,
				non-repetitive
I ² t for fusion	l ² t	41.6	A ² s	Value corresponding to 1 cycle of half wave
				50 Hz, surge on-state current
Peak gate power dissipation	P_{GM}	5	W	
Average gate power dissipation	P _G (AV)	0.5	W	
Peak gate voltage	V_{GM}	10	V	
Peak gate current	I _{GM}	2	Α	
Junction Temperature	Tj	-40 to +150	°C	
Storage temperature	Tstg	-40 to +150	°C	
Isolation voltage Note7	Viso	2000	V	Ta=25°C, AC 1 minute,
				T ₁ • T ₂ • G terminal to case

Notes: 1. Gate open.

2. Please refer to the Ordering Information.

Electrical Characteristics

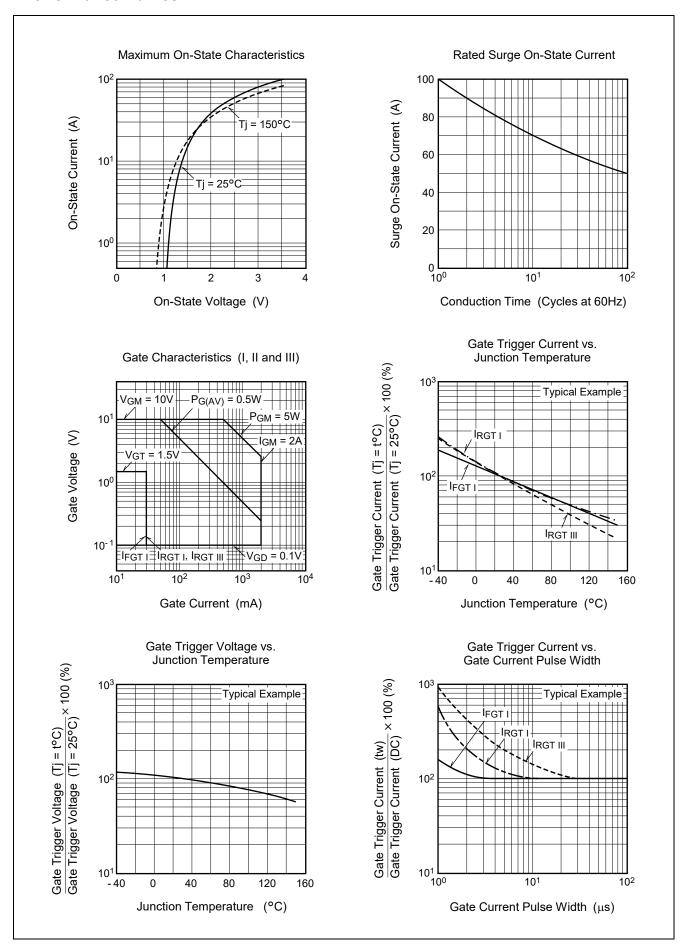
Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state cu	rrent	I _{DRM}	_	_	2.0	mA	Tj = 150°C, V _{DRM} applied
On-state voltage		V _{TM}	_	_	1.5	V	Tc = 25°C, I _{TM} = 15 A, instantaneous measurement
Gate trigger voltage ^{Note3}	I	V _{FGTI}	_	_	1.5	V	Tj = 25°C, V_D = 6 V, R_L = 6 Ω,
	II	V_{RGTI}	_	_	1.5	V	$R_G = 330 \Omega$
	III	V _{RGTIII}	_	_	1.5	V	
Gate trigger curent ^{Note3}	Gate trigger curent ^{Note3}	I _{FGTI}	_	_	30 Note6	mA	$Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω,
	II	I _{RGTI}	_	_	30 Note6	mA	$R_G = 330 \Omega$
	III	IRGTIII	_	_	30 Note6	mA	
Gate non-trigger voltage	·	V_{GD}	0.2	_	_	V	Tj = 125°C, V _D = 1/2 V _{DRM}
			0.1	_	_		Tj = 150°C, V _D = 1/2 V _{DRM}
Thermal resistance		R _{th (j-c)}	_	_	3.4	°C/W	Junction to case ^{Note4} (#BB0, #BH0) ^{Note2}
			_	_	4.1	°C/W	Junction to case ^{Note4} (#BG0) ^{Note2}
Critical-rate of rise of off-state commutation voltage ^{Note5}		(dv/dt)c	10	_	_	V/μs	Tj = 125°C
			1	_	_		Tj = 150°C

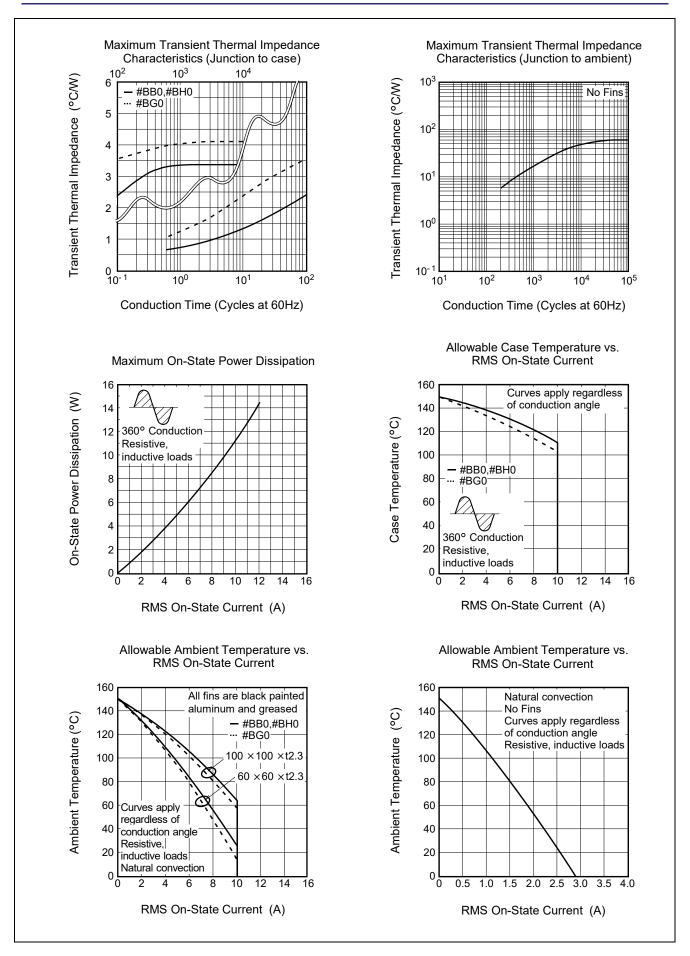
Notes: 3. Measurement using the gate trigger characteristics measurement circuit.

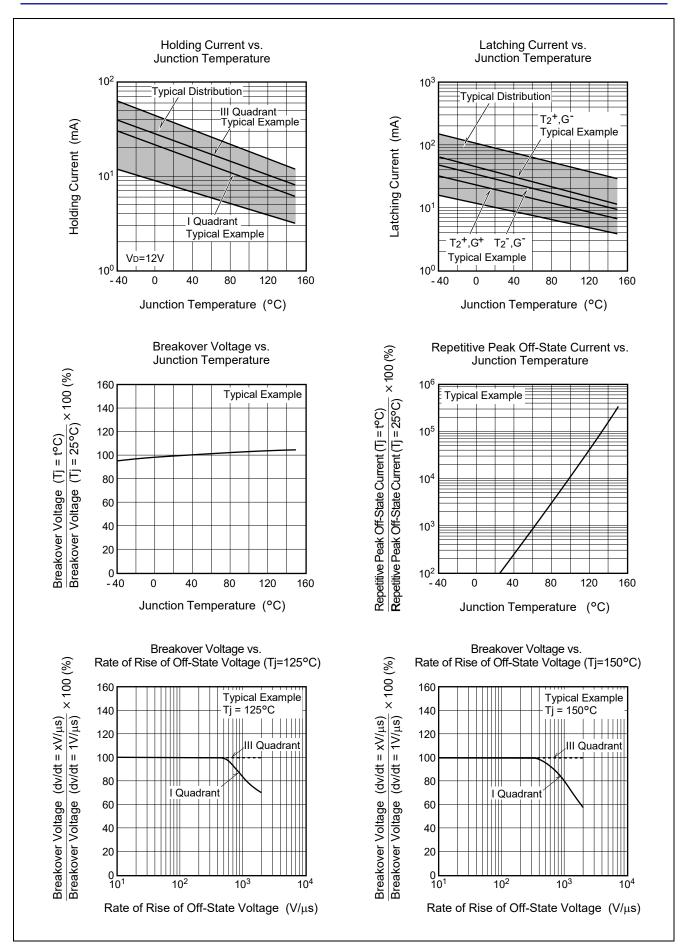
- 4. The contact thermal resistance $R_{th(c-f)}$ in case of greasing is 0.5°C/W .
- 5. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.
- 6. High sensitivity (I_{GT} ≤ 20 mA) is also available. (I_{GT} item:1)
- 7. Make sure that your finished product containing this device meets your safe isolation requirements. For safety, it's advisable that heatsink is electrically floating.

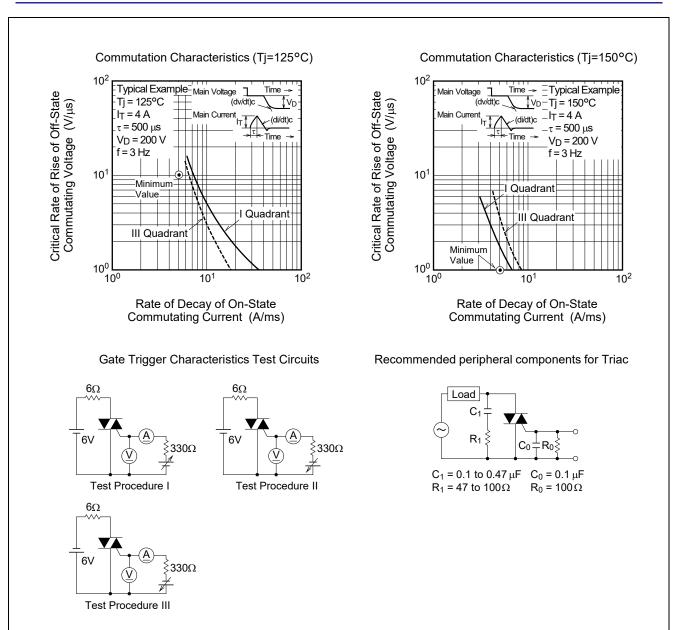
Test conditions	Commutating voltage and current waveforms (inductive load)
 Junction temperature Tj = 125°C/150°C Rate of decay of on-state commutating current (di/dt)c = -5.0 A/ms Peak off-state voltage V_D = 400 V 	Supply Voltage Main Current Main Voltage (di/dt)c Time Main Voltage (dv/dt)c

Performance Curves









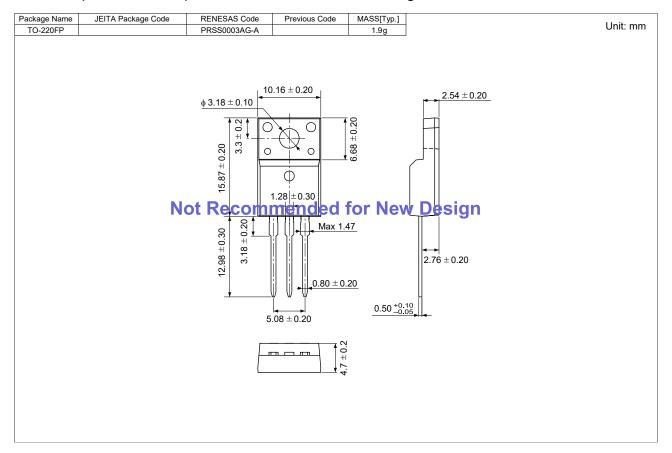
Package Dimensions

TO-220FPA (PRSS0003AP-A)

JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]	
-	PRSS0003AP-A	TO-220FPA	1.65	
10.0±0.3 10.0±0.3 10.0±0.3 10.0±0.3 2.54±0.25		7±0.2	1.65 Unit: mr	

Package Dimensions

TO-220FP (PRSS0003AG-A) <Not Recommended for New Design>



Ordering Information

Orderable Part Number	Package	Quantity Note8	Remark	Status
BCR10FM-12LB#BG0	TO-220FPA	50 pcs./ tube	Straight type	Mass Production
BCR10FM-12LB-1#BG0	TO-220FPA	50 pcs./ tube	Straight type, Ig⊤item:1	
BCR10FM-12LB□□#BG0	TO-220FPA	50 pcs./ tube	□□:Lead form type	
BCR10FM12LB1□□#BG0	TO-220FPA	50 pcs./ tube	□□:Lead form type, I _{GT} item:1	
BCR10FM-12LB#BH0	TO-220FPA	50 pcs./ tube	Straight type	Under Development
BCR10FM-12LB-1#BH0	TO-220FPA	50 pcs./ tube	Straight type, Igт item:1	
BCR10FM-12LB□□#BH0	TO-220FPA	50 pcs./ tube	□□:Lead form type	
BCR10FM12LB1□□#BH0	TO-220FPA	50 pcs./ tube	□□:Lead form type, I _{GT} item:1	
BCR10FM-12LB#BB0	TO-220FP	50 pcs./ tube	Straight type	Not Recommended for
BCR10FM-12LB□□#BB0	TO-220FP	50 pcs./ tube	□□:Lead form type	New Design

Notes: 8. Please confirm the specification about the shipping in detail.

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